

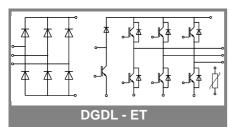
### SEMITOP<sup>®</sup>3

3-phase bridge rectifier + brake chopper + 3-phase bridge inverter SK 15 DGDL 12T4 ET

Target Data

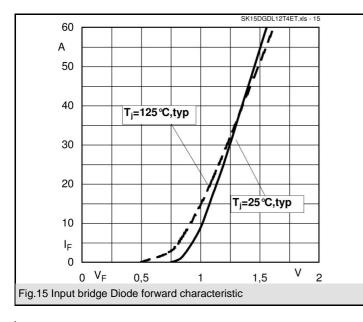
#### Features

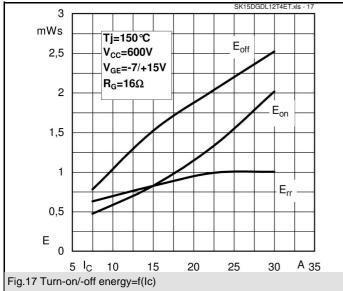
- One screw mounting module
- Trench4 IGBT technology
- CAL4 technology FWD
- Integrated NTC temperature sensor
- 1)  $V_{CE,sat}$ ,  $V_F$  = chip level value

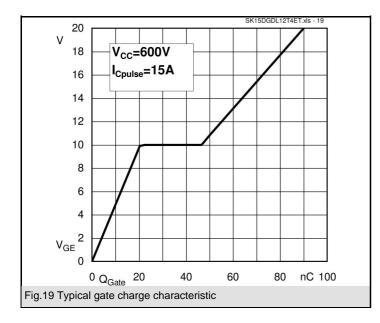


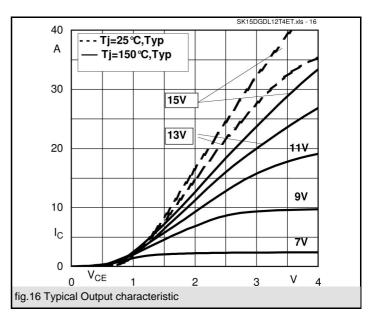
Absolute	solute Maximum Ratings Ts = 25 °C, unless otherwise sp				ecified
Symbol	Conditions		Values		Units
IGBT - In	verter,Chopper				
V <sub>CES</sub>	1		1200		V
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C		27 (21)		А
I <sub>CRM</sub>	$I_{CRM} = 3 \times I_{Cnom}, t_p = 1 \text{ ms}$		45		Α
V <sub>GES</sub>			± 20		V
T <sub>j</sub>			-40 +175		°C
	verter,Chopper				
I <sub>F</sub>	T <sub>s</sub> = 25 (70) °C		21 (17)		А
I <sub>FRM</sub>	$I_{FRM} = 2xI_{Fnom}, t_p = 1 \text{ ms}$		45		А
T <sub>i</sub>			-40 +150		°C
Rectifier					
V <sub>RRM</sub>	1		1600		V
I <sub>F</sub>	T <sub>s</sub> = 70 °C		28		А
I <sub>FSM</sub> / I <sub>TSM</sub>	t <sub>n</sub> = 10 ms , sin 180 ° ,T <sub>i</sub> = 25 °C		220		А
l <sup>2</sup> t	t <sub>n</sub> = 10 ms , sin 180 ° ,T <sub>i</sub> = 25 °C		240		A²s
T <sub>j</sub>	۲ ۲		-40 +175		°C
	Terminals, 10 s		260 °C		
I sol			200		0
T <sub>sol</sub> T <sub>sta</sub>			-40 +125		°C
T <sub>sol</sub> T <sub>stg</sub> V <sub>isol</sub>	AC, 1 min. / 1 s				_
T <sub>stg</sub>	AC, 1 min. / 1 s	Ts = 25 °C	-40 +125	herwise sp	°C V
T <sub>stg</sub> V <sub>isol</sub> Characte	AC, 1 min. / 1 s	Ts = 25 °C	-40 +125 2500 / 3000 C, unless ot	herwise sp max.	°C V
T <sub>stg</sub> V <sub>isol</sub>	AC, 1 min. / 1 s ristics  Conditions		-40 +125 2500 / 3000	•	°C V ecified
T <sub>stg</sub> V <sub>isol</sub> Characte Symbol IGBT - In <sup>v</sup>	AC, 1 min. / 1 s ristics  Conditions		-40 +125 2500 / 3000 C, unless ot <b>typ.</b>	•	°C V ecifie
T <sub>stg</sub> V <sub>isol</sub> Characte Symbol IGBT - In V <sub>CEsat</sub>	AC, 1 min. / 1 s ristics  Conditions verter		-40 +125 2500 / 3000 C, unless ot <b>typ.</b>	max.	°C V ecifie
T <sub>stg</sub> V <sub>isol</sub> Characte Symbol IGBT - In V <sub>CEsat</sub> V <sub>GE(th)</sub>	AC, 1 min. / 1 s ristics Conditions verter $I_{C} = 15 \text{ A}, T_{j} = 25 (150) ^{\circ}C$ $V_{GE} = V_{CE}, I_{C} = 0.5 \text{ mA}$ $T_{j} = 25 ^{\circ}C (150) ^{\circ}C$	min.	-40 +125 2500 / 3000 C, unless ot <b>typ.</b> 1,85 (2,25)	<b>max.</b> 2,05 (2,45)	°C V ecifie Units
$T_{stg}$ $V_{isol}$ <b>Characte</b> <b>Symbol</b> <b>IGBT - In</b> $V_{CEsat}$ $V_{GE(th)}$ $V_{CE(TO)}$	AC, 1 min. / 1 s ristics Conditions verter $I_{C} = 15 \text{ A}, T_{j} = 25 (150) ^{\circ}\text{C}$ $V_{GE} = V_{CE}, I_{C} = 0.5 \text{ mA}$ $T_{j} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $T_{i} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$	min.	-40 +125 2500 / 3000 C, unless ot <b>typ.</b> 1,85 (2,25) 5,8	<b>max.</b> 2,05 (2,45) 6,5	°C V ecifie   <b>Unit</b> s
$T_{stg}$ $V_{isol}$ <b>Characte</b> <b>Symbol</b> <b>IGBT - In</b> $V_{CEsat}$ $V_{GE(th)}$ $V_{CE(TO)}$	AC, 1 min. / 1 s ristics Conditions verter $I_{C} = 15 \text{ A}, T_{j} = 25 (150) ^{\circ}\text{C}$ $V_{GE} = V_{CE}, I_{C} = 0.5 \text{ mA}$ $T_{j} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $T_{j} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $V_{CE} = 25 V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	min.	-40 +125 2500 / 3000 C, unless ot typ. 1,85 (2,25) 5,8 1,1 (1)	<b>max.</b> 2,05 (2,45) 6,5	°C V ecified Units V V V
$T_{stg}$ $V_{isol}$ <b>Characte</b> <b>Symbol</b> <b>IGBT - Inv</b> $V_{CEsat}$ $V_{GE(th)}$ $V_{CE(TO)}$ $f_T$ $C_{ies}$ $C_{oes}$	AC, 1 min. / 1 s ristics Conditions verter $I_{C} = 15 \text{ A}, T_{j} = 25 (150) \text{ °C}$ $V_{GE} = V_{CE}, I_{C} = 0,5 \text{ mA}$ $T_{j} = 25 \text{ °C} (150) \text{ °C}$ $T_{j} = 25 \text{ °C} (150) \text{ °C}$ $V_{CE} = 25 V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	min.	-40 +125 2500 / 3000 C, unless ot typ. 1,85 (2,25) 5,8 1,1 (1) 50 (83,3)	<b>max.</b> 2,05 (2,45) 6,5	°C V ecified Units Units V V V V
T <sub>stg</sub> V <sub>isol</sub> Characte Symbol IGBT - Inv V <sub>CEsat</sub> V <sub>GE(th)</sub> V <sub>CE(TO)</sub> r <sub>T</sub> C <sub>ies</sub>	AC, 1 min. / 1 s ristics Conditions verter $I_{C} = 15 \text{ A}, T_{j} = 25 (150) ^{\circ}\text{C}$ $V_{GE} = V_{CE}, I_{C} = 0.5 \text{ mA}$ $T_{j} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $T_{j} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $V_{CE} = 25 V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	min.	-40 +125 2500 / 3000 C, unless ot typ. 1,85 (2,25) 5,8 1,1 (1) 50 (83,3) 0,9	<b>max.</b> 2,05 (2,45) 6,5	°C V ecifie Units Units V V V MΩ nF
$T_{stg}$ $V_{isol}$ <b>Characte</b> <b>Symbol</b> <b>IGBT - Inv</b> $V_{CEsat}$ $V_{GE(th)}$ $V_{CE(TO)}$ $f_T$ $C_{ies}$ $C_{oes}$	AC, 1 min. / 1 s ristics Conditions verter $I_{C} = 15 \text{ A}, T_{j} = 25 (150) \text{ °C}$ $V_{GE} = V_{CE}, I_{C} = 0,5 \text{ mA}$ $T_{j} = 25 \text{ °C} (150) \text{ °C}$ $T_{j} = 25 \text{ °C} (150) \text{ °C}$ $V_{CE} = 25 V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	min.	-40 +125 2500 / 3000 C, unless of typ. 1,85 (2,25) 5,8 1,1 (1) 50 (83,3) 0,9 0,08	<b>max.</b> 2,05 (2,45) 6,5	°C V   <b>Unit</b> s   V V ν mΩ nF nF
T <sub>stg</sub> V <sub>isol</sub> Characte Symbol IGBT - In V <sub>CEsat</sub> V <sub>GE(th)</sub> V <sub>CE(TO)</sub> f <sub>T</sub> C <sub>ies</sub> C <sub>oes</sub> C <sub>res</sub>	AC, 1 min. / 1 s ristics Conditions verter $I_{C} = 15 \text{ A}, T_{j} = 25 (150) ^{\circ}\text{C}$ $V_{GE} = V_{CE}, I_{C} = 0.5 \text{ mA}$ $T_{j} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $V_{CE} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $V_{CE} = 25 ^{\circ}\text{C} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}\text{V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}\text{V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $P_{CE} = 25 ^{\circ}\text{V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $P_{CE} = 10 \text{ MHz}$ $P_{CE} = 10 \text{ MHz}$ $P_{CE} = 10 \text{ MHz}$ $P_{CE} = 10 \text{ MHz}$ $V_{CE} = 10 \text{ MHz}$	min.	-40 +125 2500 / 3000 C, unless ot typ. 1,85 (2,25) 5,8 1,1 (1) 50 (83,3) 0,9 0,08 0,055 1,65 16	<b>max.</b> 2,05 (2,45) 6,5	°C V ecified Units V V MΩ nF nF nF
$T_{stg}$ $V_{isol}$ <b>Characte</b> <b>Symbol</b> <b>IGBT - In</b> $V_{CEsat}$ $V_{CE(th)}$ $V_{CE(TO)}$ $T_{T}$ $C_{ies}$ $C_{res}$ $R_{th(j-s)}$	AC, 1 min. / 1 s ristics Conditions verter $I_{c} = 15 \text{ A}, T_{j} = 25 (150) ^{\circ}C$ $V_{GE} = V_{CE}, I_{c} = 0.5 \text{ mA}$ $T_{j} = 25 ^{\circ}C (150) ^{\circ}C$ $V_{CE} = 25 ^{\circ}V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$	min.	-40 +125 2500 / 3000 C, unless ot typ. 1,85 (2,25) 5,8 1,1 (1) 50 (83,3) 0,9 0,08 0,055 1,65 16 14	<b>max.</b> 2,05 (2,45) 6,5	°C V eccified Units V V V N Ω nF nF K/W
$T_{stg}$ $V_{isol}$ <b>Characte</b> <b>Symbol</b> <b>IGBT - In</b> $V_{CEsat}$ $V_{CE(TO)}$ $T_{T}$ $C_{ies}$ $C_{res}$ $C_{res}$ $R_{th(j-s)}$ $t_{d(on)}$	AC, 1 min. / 1 s ristics Conditions verter $I_{c} = 15 \text{ A}, T_{j} = 25 (150) ^{\circ}\text{C}$ $V_{GE} = V_{CE}, I_{c} = 0.5 \text{ mA}$ $T_{j} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $V_{CE} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $V_{CE} = 25 ^{\circ}\text{C} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}\text{V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}\text{V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}\text{V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 26 ^{\circ}\text{V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 600 \text{ V}, V_{CE} = \pm 15 \text{ V}$ $I_{c} = 15 \text{ A}, T_{j} = 150 ^{\circ}\text{C}$	min.	-40 +125 2500 / 3000 C, unless ott typ. 1,85 (2,25) 5,8 1,1 (1) 50 (83,3) 0,9 0,08 0,055 1,65 16 14 273	<b>max.</b> 2,05 (2,45) 6,5	°C V eccified Units V V V N Ω nF nF K/W ns
$T_{stg}$ $V_{isol}$ <b>Characte</b> <b>Symbol</b> <b>IGBT - In</b> $V_{CEsat}$ $V_{CE(TO)}$ $T_{T}$ $C_{ies}$ $C_{res}$ $R_{th(j-s)}$ $t_{d}(on)$ $t_{r}$ $t_{d}(off)$ $t_{f}$	AC, 1 min. / 1 s ristics Conditions verter $I_C = 15 \text{ A}, T_j = 25 (150) \text{ °C}$ $V_{GE} = V_{CE}, I_C = 0.5 \text{ mA}$ $T_j = 25 \text{ °C} (150) \text{ °C}$ $V_{CE} = 25 \text{ V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 \text{ V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 \text{ V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 \text{ V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 \text{ V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 \text{ V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 16 \text{ G}$ under following conditions $V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$ $I_C = 15 \text{ A}, T_j = 150 \text{ °C}$ $R_{Gon} = R_{Goff} = 16 \Omega$	min.	-40 +125 2500 / 3000 C, unless of typ. 1,85 (2,25) 5,8 1,1 (1) 50 (83,3) 0,9 0,08 0,055 1,65 16 14 273 85	<b>max.</b> 2,05 (2,45) 6,5	°C V <b>Unit:</b> V V V MΩ nF nF K/W ns ns
$T_{stg}$ $V_{isol}$ <b>Characte</b> <b>Symbol</b> <b>IGBT - In</b> $V_{CEsat}$ $V_{CE(TO)}$ $T_{T}$ $C_{ies}$ $C_{res}$ $R_{th(j-s)}$ $t_{d(on)}$ $t_{r}$ $t_{d(off)}$	AC, 1 min. / 1 s ristics Conditions verter $I_{c} = 15 \text{ A}, T_{j} = 25 (150) ^{\circ}\text{C}$ $V_{GE} = V_{CE}, I_{c} = 0.5 \text{ mA}$ $T_{j} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $V_{CE} = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $V_{CE} = 25 ^{\circ}\text{C} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}\text{V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}\text{V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 ^{\circ}\text{V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 26 ^{\circ}\text{V}_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 600 \text{ V}, V_{CE} = \pm 15 \text{ V}$ $I_{c} = 15 \text{ A}, T_{j} = 150 ^{\circ}\text{C}$	min.	-40 +125 2500 / 3000 C, unless ott typ. 1,85 (2,25) 5,8 1,1 (1) 50 (83,3) 0,9 0,08 0,055 1,65 16 14 273	<b>max.</b> 2,05 (2,45) 6,5	°C V <b>Unit:</b> V V MΩ nF nF K/W ns ns ns

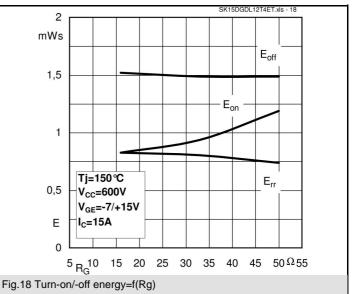
UII							
Diode - Inverter, Chopper							
$V_F = V_{EC}$	I <sub>F</sub> = 15 A, T <sub>i</sub> = 25(150) °C	2,38 (2,44) 2,71 (2,7	7) V				
V <sub>(TO)</sub>	T <sub>i</sub> = 25 °C (150) °C	1,3 (0,9) 1,5 (1,1)	) V				
r <sub>T</sub>	T <sub>j</sub> = 25 °C (150) °C	72 (102,7) 80,6 (111,3)	mΩ				
R <sub>th(j-s)</sub>	per diode	2,34	K/W				
I <sub>RRM</sub>	under following conditions	28	Α				
Q <sub>rr</sub>	I <sub>F</sub> = 15 A, V <sub>R</sub> = V	0,3	μC				
Err	V <sub>GE</sub> = 0 V, T <sub>j</sub> = 150 °C	0,82	mJ				
	di <sub>F/dt</sub> = 2750 A/µs						
Diode - Rectifier							
V <sub>F</sub>	I <sub>F</sub> = 15 A, T <sub>i</sub> = 25() °C	1,1	V				
V <sub>(TO)</sub>	T <sub>j</sub> = 150 °C	0,9	V				
r <sub>T</sub>	T <sub>j</sub> = 150 °C	20	mΩ				
R <sub>th(j-s)</sub>	per diode	2	K/W				
Temperatur sensor							
R <sub>ts</sub>	5 %, T <sub>r</sub> = 25 (100 ) °C	5000(493)	Ω				
Mechanica	Mechanical data						
w		30	g				
M <sub>s</sub>	Mounting torque	2,25 2,5	Nm				

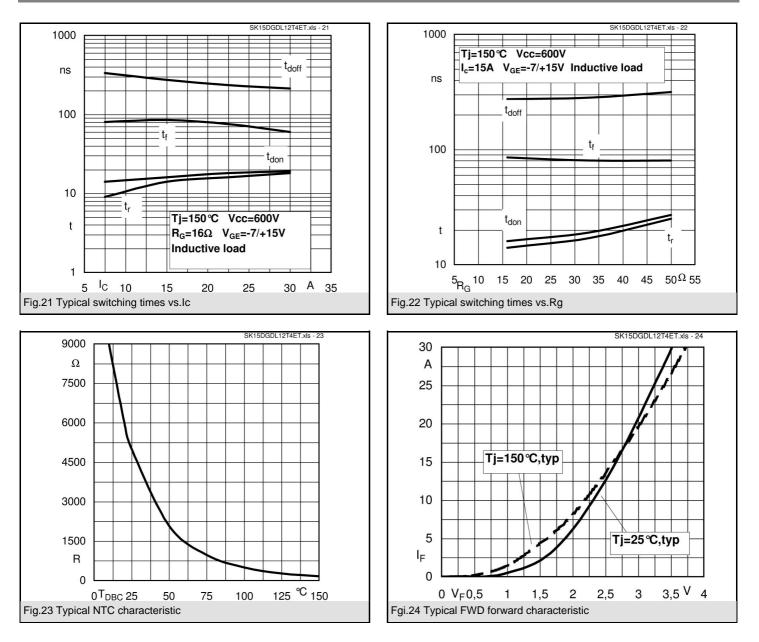


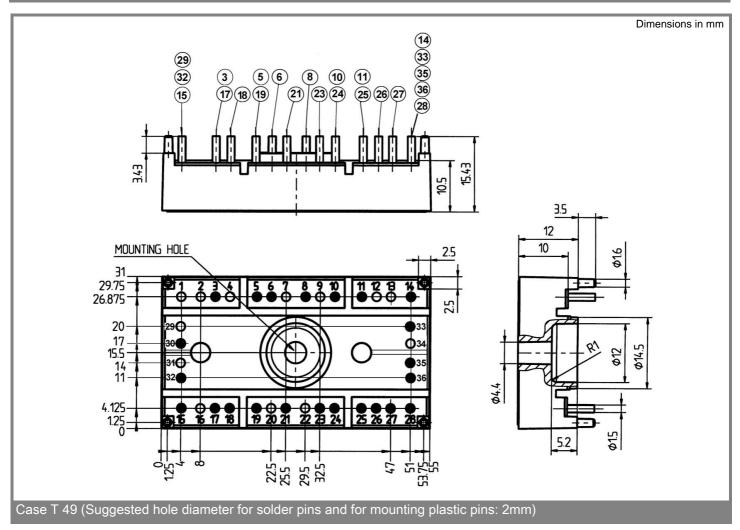


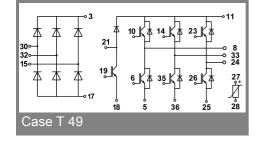












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

\* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.